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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/544,801	04/07/2000	Shenpei Yamazaki	SEL 174	1717

7590 02/18/2003

Cook Alex McFarron Manzo Cummings & Mehler LTD
200 West Adams Street Suite 2850
Chicago, IL 60606

[REDACTED] EXAMINER

ERDEM, FAZLI

ART UNIT	PAPER NUMBER
2826	13

DATE MAILED: 02/18/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	09/544,801	YAMAZAKI ET AL.
	Examiner	Art Unit
	Fazli Erdem	2826

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 26 December 2002.

2a) This action is FINAL. 2b) This action is non-final.

3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1-27 and 64-79 is/are pending in the application.

4a) Of the above claim(s) _____ is/are withdrawn from consideration.

5) Claim(s) _____ is/are allowed.

6) Claim(s) 1,3,4,6,8,9,10,12,13,15,17,18,19,21,22,24,26,27,64-79 is/are rejected.

7) Claim(s) 2,5,7, 11,14,16,20,23,25 is/are objected to.

8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.

10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).

11) The proposed drawing correction filed on _____ is: a) approved b) disapproved by the Examiner.
If approved, corrected drawings are required in reply to this Office action.

12) The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
a) All b) Some * c) None of:
1. Certified copies of the priority documents have been received.
2. Certified copies of the priority documents have been received in Application No. _____.
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).
a) The translation of the foreign language provisional application has been received.

15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892)	4) <input type="checkbox"/> Interview Summary (PTO-413) Paper No(s). _____
2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)	5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152)
3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____	6) <input type="checkbox"/> Other: _____

DETAILED ACTION

Allowable Subject Matter

1. Claims 2, 5, 7, 11, 14, 16, 20, 23, 25 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 1, 3, 4, 6, 8, and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamanaka et al. (6,504,215) in view of Kobayashi et al. (6,146,930).

Regarding Claims 1,3,4,6,8, and 9, Yamanaka et al. disclose an electro-optical apparatus having a display section and a peripheral driving circuit section where a single crystal silicon is graphoepitaxially grown using a step formed on a substrate as a seed by a catalyst process, and the obtained single crystal silicon layer is used for a dual gate type MOSTFT in an electro-optical apparatus such as a display section of a peripheral driving circuit integration type LCD. A single crystal silicon thin film having high electron/hole mobility is formed into a uniform film at a relatively low temperature which enables the manufacturing of an active matrix substrate incorporated with a high performance driver which can be used in a TFT display. Yamanaka et al. do not show the required gate wiring structure. However, Kobayashi et al. disclose a method of fabricating an active-matrix liquid crystal display where an active-matrix liquid crystal display

integrally formed with a driver circuit including a pair of substrates disposed in opposing relation to each other and a liquid crystal material sandwiched between the pair of substrates.

Furthermore, Kobayashi et al. disclose the required gate wiring structure.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required gate wiring structure in Yamanaka et al. as taught by Kobayashi et al. in order to have an LCD device with higher performance.

3. Claims 10, 12, 13, 15, 17, 18, 19, 21, 22, 24, 26, 27 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamanaka et al. (6,504,215) in view of Kobayashi et al. (5,767,930).

Regarding Claims 10, 12, 13, 15, 17, 18, 19, 21, 22, 24, 26, 27 Yamanaka et al. disclose an electro-optical apparatus having a display section and a peripheral driving circuit section where a single crystal silicon is graphoepitaxially grown using a step formed on a substrate as a seed by a catalyst process, and the obtained single crystal silicon layer is used for a dual gate type MOSTFT in an electro-optical apparatus such as a display section of a peripheral driving circuit integration type LCD. A single crystal silicon thin film having high electron/hole mobility is formed into a uniform film at a relatively low temperature which enables the manufacturing of an active matrix substrate incorporated with a high performance driver which can be used in a TFT display. Yamanaka et al. do not show the required gate wiring structure. However, Kobayashi et al. disclose an active-matrix liquid crystal display and fabrication method thereof where an active-matrix liquid crystal display integrally formed with a driver circuit including a pair of substrates disposed in opposing relation to each other and a liquid

crystal material sandwiched between the pair of substrates. Furthermore, Kobayashi et al. disclose the required gate wiring structure.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required gate wiring structure in Yamanaka et al. as taught by Kobayashi et al. in order to have an LCD device with higher performance.

4. Claims 64, 66, 67, 68, 70, 71, 72, 74, 75, 76, 78, 79 are rejected under 35 U.S.C. 103(a) as being unpatentable over Seo (6,323,068) in view of Kobayashi et al. (5,767,930).

Regarding Claims 64, 66, 67, 68, 70, 71, 72, 74, 75, 76, 78, 79, Seo discloses a liquid crystal display device integrated with driving circuit and method for fabricating the same where a method is provided for fabricating an LCD device integrated with a driver circuit on a substrate. A surface of the substrate is divided into a p-channel region, an n-channel region, and a pixel region. The method includes the steps of forming a gate electrode on each of the p-channel and n-channel, and pixel regions of the substrate, forming a gate insulating layer on the entire surface of the substrate including the gate electrodes, forming a first transparent electrode layer over the gate insulating layer, forming a conductive layer over the first transparent electrode layer, forming a second transparent electrode layer over the conductive layer, removing portions of the first transparent electrode layer, the conductive layer and the second transparent electrode layer for form source/drain electrodes adjacent the gate electrodes in each of the p-channel, n-channel, and pixel regions of the substrate, doping first impurities into the second transparent electrode layer in the p-channel region, doping second impurities into the second transparent electrode layer in the n-channel region and in the pixel region, forming a semiconductor layer over the

entire surface of the substrate, annealing the semiconductor layer, forming a passivation layer over the entire surface of the substrate and removing portions of the passivation layer, the second transparent electrode, and the conductive layer in the pixel region to expose a portion of the first transparent electrode layer. Seo does not disclose the required gate wiring structure. However, Kobayashi et al. disclose an active matrix liquid crystal display and fabrication method where the gate wiring structure is shown.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required gate wiring structure in Seo as taught by Kobayashi et al. in order to have an LCD device with higher performance.

5. Claims 65, 69 are rejected under 35 U.S.C. 103(a) as being unpatentable over Seo (6,323,068) in view of Kobayashi et al. (5,767,930) further in view of Iwanaga et al. (6,150,692).

Regarding Claims 65 and 69, Seo and Kobayashi combination disclose all the claimed subject matter except they fail to show the required conductive structure. However, Iwanaga et al. disclose a thin film semiconductor device for active matrix panel where the required conductive structure is shown.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required conductive structure in Seo and Kobayashi et al. combination as taught by Iwanaga et al. in order to have an LCD device with higher performance.

6. Claims 73 and 77 are rejected under 35 U.S.C. 103(a) as being unpatentable over Seo (6,323,068) in view of Kobayashi et al. (5,767,930) further in view of Sasano et al. (5,671,027)

Regarding Claims 73 and 77, Seo and Kobayashi combination disclose all the claimed subject matter except they fail to show the required conductive structure. However, Sasano et al. disclose a thin film semiconductor device for active matrix panel where the required conductive structure is shown.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required conductive structure in Seo and Kobayashi et al. combination as taught by Sasano et al. in order to have an LCD device with higher performance.

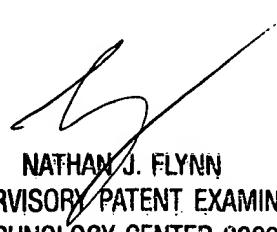
Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (703) 305-3868. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (703) 308-6601. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

FE
February 10, 2003


NATHAN J. FLYNN
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800